XCL210 Series

50mA/200mA Inductor Built-in Step-Down "micro DC/DC" Converters

Preliminary

☆GreenOperationCompatible

■GENERAL DESCRIPTION

The XCL210 series is a synchronous step-down micro DC/DC converter which integrates an inductor and a control IC in one tiny package (2.0mm×2.5mm, h=1.0mm). An internal coil simplifies the circuit and enables minimization of noise and other operational trouble due to the circuit wiring. A wide operating voltage range of 2.0V to 6.0V enables support for applications that require an internally fixed output voltage from 1.0V to 4.0V in increments of 0.1V.

During stand-by, all circuits are shutdown to reduce currentconsumption to as low as 0.1µA or less.

With the built-in UVLO (Under Voltage Lock Out) function, the internal P-channel MOS driver transistor is forced OFF when input voltage becomes UVLO dictect Voltage or lower.

The XCL210 integrate C_L discharge function which enables the electric charge at the output capacitor C_L to be discharged via the internal discharge switch located between the L_x and V_{SS} pins. When the devices enter stand-by mode, output voltage quickly returns to the V_{SS} level as a result of this function.

■APPLICATIONS

- Wearable Devices
- Smart meters
- Bluetooth units
- Energy Harvest devices
- Back up power supply circuits
- Portable game consoles
- Devices with 1 Lithium cell

■FEATURES

Input Voltage	:	2.0V～6.0V
Output Voltage	:	1.0V～4.0V (±2.0%, 0.1V step increments)
Control Methods	:	PFM control
Output Current	**:**	200mA(XCL210A/XCL210C)
		50mA(XCL210B/XCL210D)
Supply Current	**:**	0.5µA
High Efficiency	:	93% (V_{IN}=3.6V,V_{OUT}=3.0V/100µA)
Function	:	UVLO
		Short Circuit Protection
	:	C_L Discharge
Capacitor	:	Low ESR Ceramic Capacitor
Operating Ambient Temperature	:	-40℃～+85℃
Packages	:	CL-2025-02
Environmentally Friendly	:	EU RoHS Compliant, Pb Free

■TYPICAL APPLICATION CIRCUIT

■TYPICAL PERFORMANCE CHARACTERISTICS

XCL210B301GR-G(V_{OUT}=3.0V)
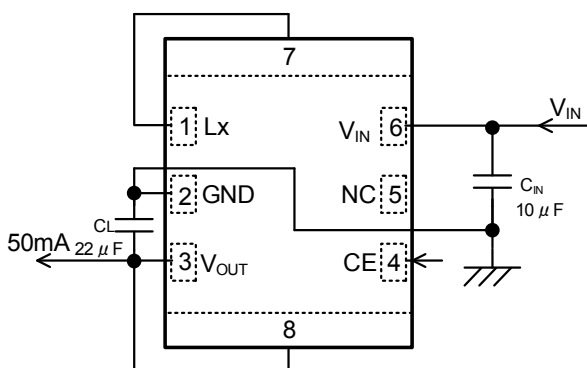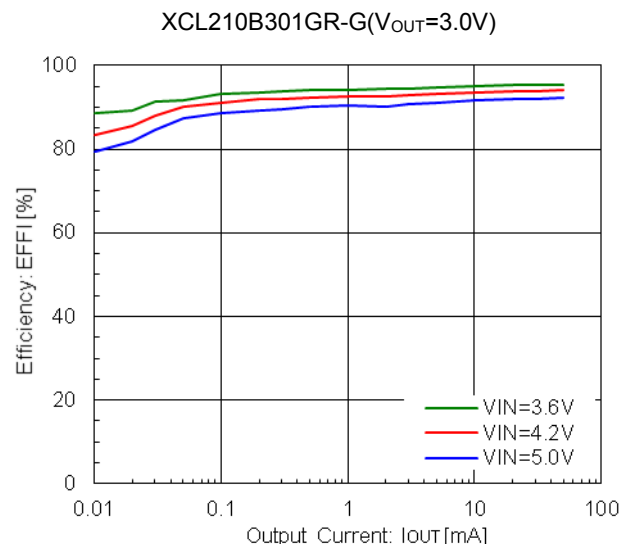
■BLOCK DIAGRAM
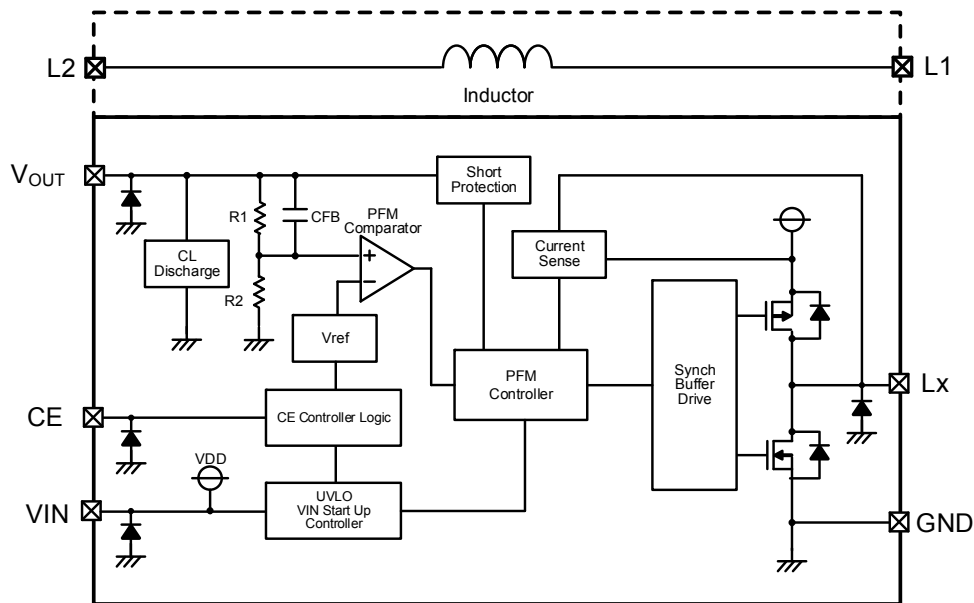
* Diodes inside the circuits are ESD protection diodes and parasitic diodes.

XCL210A and B type do not have C_L Discharge function.

■PRODUCT CLASSIFICATION

●Ordering information

XCL210①②③④⑤⑥-⑦

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Product Type	A	I_{OUT}=200mA , Without C_L Auto Discharge
		B	I_{OUT}=50mA Without C_L Auto Discharge
		C	I_{OUT}=200mA , With C_L Auto Discharge
		D	I_{OUT}=50mA, With C_L Auto Discharge
②③	Output Voltage	10～40	Output Voltage e.g. V_{OUT}=1.8V ⇒ ②=1、③=8
④	Fixed number	1	Fixed number
⑤⑥-⑦(*1)	Package (Order Unit)	GR-G	CL-2025-02（3,000pcs/Reel）

(*1) The "-G" suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.。

■PIN CONFIGURATION
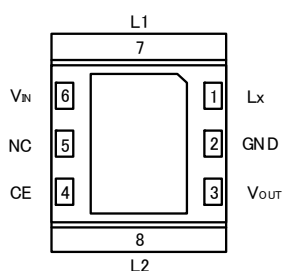
（BOTTOM VIEW）

* The dissipation pad for the CL-2025-02 package should be solder-plated in recommended mount pattern and metal masking so as to enhance mounting strength and heat release.

The mount pattern should be connected to GND pin (No.2).

■PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTIONS
1	L_X	Switching
2	GND	Ground
3	V_{OUT}	Output Voltage
4	CE	Chip Enable
5	NC	Ground
6	V_{IN}	Power Input
7	L1	Inductor Electrodes
8	L2	Inductor Electrodes

■CE PIN FUNCTION

PIN NAME	SIGNAL	STATUS
CE	H	Operation (ALLSeries)
	L	Standby (ALL Series)

* Please do not leave the CE pin open.

■ABSOLUTE MAXIMUM RATINGS

Ta=25˚C

PARAMETER	SYMBOL	RATINGS	UNITS
V_{IN} Pin Voltage	V_{IN}	-0.3 ~ +7.0	V
L_X Pin Voltage	V_{LX}	-0.3 ~ V_{IN}+0.3 or +7.0 [(*1)]	V
V_{OUT} Pin Voltage	V_{OUT}	-0.3 ~ V_{IN}+0.3 or +7.0 [(*1)]	V
CE Pin Voltage	V_{CE}	-0.3 ~ +7.0	V
L_X Pin Current	I_{LX}	1000	mA
Power Dissipation	Pd	1000	mW
Operating Ambient Temperature	Topr	-40 ~ +85	˚C
Storage Temperature	Tstg	-55 ~ +125	˚C

* All voltages are described based on the GND.

[(*1)] The maximum value is the lower of either V_{IN} + 0.3 or +7.0.

■ELECTRICAL CHARACTERISTICS

● XCL210Axx1GR-G, without C_L discharge function

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}	-	2.0	-	6.0	V	①
Output Voltage	$V_{OUT(E)}$ [*2]	Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{OUT} is decreasing.	E1			V	②
UVLO Release Voltage	$V_{UVLO(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{IN} is increasing.	1.65	1.80	1.95	V	②
UVLO Hysteresis Voltage	$V_{HYS(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. $V_{UVLO(E)}$ - Voltage which L_X pin changes "H" to "L" level while V_{IN} is decreasing.	0.11	0.15	0.24	V	②
Supply Current	Iq	$V_{IN}=V_{CE}=V_{OUT(T)}+0.5V$ [*1], $V_{IN}=2.0V$, if $V_{OUT(T)} \leqq 1.5V$ [*1], $V_{OUT}=V_{OUT(T)}+0.5V$ [*1], L_X=Open.	E2			µA	③
Standby Current	I_{STB}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-	0.1	1.0	µA	③
L_X SW "H" Leak Current	I_{LEAKH}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=0V$.	-	0.1	1.0	µA	③
L_X SW "L" Leak Current	I_{LEAKL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=5.0V$.	-	0.1	1.0	µA	③
PFM Switching Current	I_{PFM}	$V_{IN}=V_{CE}=V_{OUT(T)}+2.0V$ [*1], $I_{OUT}=10mA$.	260	330	400	mA	①
Maximum Duty Ratio [*3]	MAXDTY	$V_{IN}=V_{OUT}=V_{OUT(T)} \times 0.95V$ [*1], $V_{CE}=1.2V$ Resistor connected with L_X pin.	100	-	-	%	②
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=5.0V$, $V_{OUT(T)}=4.0V$ [*1], $I_{OUT}=30mA$.	-	93	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=3.3V$ [*1], $I_{OUT}=30mA$.	-	93	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=1.8V$ [*1], $I_{OUT}=30mA$.	-	87	-	%	①
L_X SW "Pch" ON Resistance [*5]	R_{LXP}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, $I_{LX}=100mA$.	-	0.4	0.65	Ω	④
L_X SW "Nch" ON Resistance	R_{LXN}	$V_{IN}=V_{CE}=5.0V$.	-	0.4 [*6]	-	Ω	-
Output Voltage Temperature Characteristics	$\Delta V_{OUT}/(V_{OUT} \cdot \Delta Topr)$	$-40°C \leqq Topr \leqq 85°C$.	-	±100	-	ppm/°C	②
CE "High" Voltage	V_{CEH}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while $V_{CE}=0.2 \rightarrow 1.5V$.	1.2	-	6.0	V	⑤
CE "Low" Voltage	V_{CEL}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{CE}=1.5 \rightarrow 0.2V$.	GND	-	0.3	V	⑤
CE "High" Current	I_{CEH}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	µA	⑤
CE "Low" Current	I_{CEL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	µA	⑤
Short Protection Threshold Voltage	V_{SHORT}	Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{OUT}=V_{OUT(T)}+0.1V \rightarrow 0V$ [*1].	0.4	0.5	0.6	V	②
Inductance Value	L	Test Frequency=1MHz	-	8.0	-	µH	
(Coil) Rated Current	I_{DC_L}	$\Delta T=+40°C$	-	600	-	mA	

Unless otherwise stated, $V_{IN}=V_{CE}=5.0V$

[*1] $V_{OUT(T)}$=Nominal Output Voltage

[*2] $V_{OUT(E)}$=Effective Output Voltage

The actual output voltage value $V_{OUT(E)}$ is the PFM comparator threshold voltage in the IC.

Therefore, the DC/DC circuit output voltage, including the peripheral components, is boosted by the ripple voltage average value.

Please refer to the characteristic example.

[*3] Not applicable to the products with $V_{OUT(T)} < 2.2V$ since it is out of operational volatge range.

[*4] EFFI=[{ (Output Voltage)×(Output Current)] / [(Input Voltage)×(Input Current)}]×100

[*5] L_X SW "Pch" ON resistance = (V_{IN} – V_{LX} pin measurement voltage) / 100mA

[*6] Designed value

Preliminary

■ELECTRICAL CHARACTERISTICS (Continued)

●XCL210Bxx1GR-G, without C_L discharge function

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}	-	2.0	-	6.0	V	①
Output Voltage	$V_{OUT(E)}$ [*2]	Resistor connected with L_X pin.Voltage which L_X pin changes "L" to "H" level while V_{OUT} is decreasing.	E1			V	②
UVLO Release Voltage	$V_{UVLO(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{IN} is increasing.	1.65	1.80	1.95	V	②
UVLO Hysteresis Voltage	$V_{HYS(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. $V_{UVLO(E)}$ - Voltage which L_X pin changes "H" to "L" level while V_{IN} is decreasing.	0.11	0.15	0.24	V	②
Supply Current	Iq	$V_{IN}=V_{CE}=V_{OUT(T)}+0.5V$ [*1],$V_{IN}=2.0V$, if $V_{OUT(T)}≦1.5V$ [*1], $V_{OUT}=V_{OUT(T)}+0.5V$ [*1], L_X=Open.	E2			μA	③
Standby Current	I_{STB}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-	0.1	1.0	μA	③
L_X SW "H" Leak Current	I_{LEAKH}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=0V$.	-	0.1	1.0	μA	③
L_X SW "L" Leak Current	I_{LEAKL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=5.0V$.	-	0.1	1.0	μA	③
PFM Switching Current	I_{PFM}	$V_{IN}=V_{CE}=V_{OUT(T)}+2.0V$ [*1], $I_{OUT}=10mA$.	115	180	250	mA	①
Maximum Duty Ratio [*3]	MAXDTY	$V_{IN}=V_{OUT}=V_{OUT(T)}×0.95V$ [*1], $V_{CE}=1.2V$ Resistor connected with L_X pin.	100	-	-	%	②
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=5.0V$,$V_{OUT(T)}=4.0V$ [*1], $I_{OUT}=30mA$.	-	95	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=3.3V$ [*1], $I_{OUT}=30mA$.	-	95	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=1.8V$ [*1], $I_{OUT}=30mA$.	-	89	-	%	①
L_X SW "Pch" ON Resistance [*5]	R_{LXP}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, $I_{LX}=100mA$.	-	0.4	0.65	Ω	④
L_X SW "Nch" ON Resistance	R_{LXN}	$V_{IN}=V_{CE}=5.0V$.	-	0.4 [*6]	-	Ω	-
Output Voltage Temperature Characteristics	$ΔV_{OUT}/$ $(V_{OUT}·ΔTopr)$	-40℃≦Topr≦85℃.	-	±100	-	ppm/℃	②
CE "High" Voltage	V_{CEH}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while $V_{CE}=0.2→1.5V$.	1.2	-	6.0	V	⑤
CE "Low" Voltage	V_{CEL}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{CE}=1.5→0.2V$.	GND	-	0.3	V	⑤
CE "High" Current	I_{CEH}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	μA	⑤
CE "Low" Current	I_{CEL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	μA	⑤
Short Protection Threshold Voltage	V_{SHORT}	Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{OUT}=V_{OUT(T)}+0.1V→0V$ [*1].	0.4	0.5	0.6	V	②
Inductance Value	L	Test Frequency=1MHz	-	8.0	-	μH	
(Coil) Rated Current	I_{DC_L}	ΔT=+40℃	-	600	-	mA	

Unless otherwise stated, $V_{IN}=V_{CE}=5.0V$

[*1] $V_{OUT(T)}$=Nominal Output Voltage

[*2] $V_{OUT(E)}$=Effective Output Voltage

The actual output voltage value $V_{OUT(E)}$ is the PFM comparator threshold voltage in the IC.

Therefore, the DC/DC circuit output voltage, including the peripheral components, is boosted by the ripple voltage average value.

Please refer to the characteristic example.

[*3] Not applicable to the products with $V_{OUT(T)}$ < 2.2V since it is out of operational volatge range.

[*4] EFFI=[{ (Output Voltage)×(Output Current] / [(Input Voltage)×(Input Current)}]×100

[*5] L_X SW "Pch" ON resistance = (V_{IN} – V_{LX} pin measurement voltage) / 100mA

[*6] Designed value

■ELECTRICAL CHARACTERISTICS (Continued)

● XCL210Cxx1GR-G, with C_L Discharge Function

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}	-	2.0	-	6.0	V	①
Output Voltage	$V_{OUT(E)}$ [*2]	Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{OUT} is decreasing.	E1			V	②
UVLO Release Voltage	$V_{UVLO(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{IN} is increasing.	1.65	1.80	1.95	V	②
UVLO Hysteresis Voltage	$V_{HYS(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. $V_{UVLO(E)}$ - Voltage which L_X pin changes "H" to "L" level while V_{IN} is decreasing.	0.11	0.15	0.24	V	②
Supply Current	Iq	$V_{IN}=V_{CE}=V_{OUT(T)}+0.5V$ [*1], $V_{IN}=2.0V$, if $V_{OUT(T)}≦1.5V$ [*1], $V_{OUT}=V_{OUT(T)}+0.5V$ [*1], L_X=Open.	E2			µA	③
Standby Current	I_{STB}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-	0.1	1.0	µA	③
L_X SW "H" Leak Current	I_{LEAKH}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=0V$.	-	0.1	1.0	µA	③
L_X SW "L" Leak Current	I_{LEAKL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=5.0V$.	-	0.1	1.0	µA	③
PFM Switching Current	I_{PFM}	$V_{IN}=V_{CE}=V_{OUT(T)}+2.0V$ [*1], $I_{OUT}=10mA$.	260	330	400	mA	①
Maximum Duty Ratio [*3]	MAXDTY	$V_{IN}=V_{OUT}=V_{OUT(T)}×0.95V$ [*1], $V_{CE}=1.2V$ Resistor connected with L_X pin.	100	-	-	%	②
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=5.0V$, $V_{OUT(T)}=4.0V$ [*1], $I_{OUT}=30mA$.	-	93	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=3.3V$ [*1], $I_{OUT}=30mA$.	-	93	-	%	①
Efficiency [*4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=1.8V$ [*1], $I_{OUT}=30mA$.	-	87	-	%	①
L_X SW "Pch" ON Resistance [*5]	R_{LXP}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, $I_{LX}=100mA$.	-	0.4	0.65	Ω	④
L_X SW "Nch" ON Resistance	R_{LXN}	$V_{IN}=V_{CE}=5.0V$.	-	0.4 [*6]	-	Ω	-
Output Voltage Temperature Characteristics	$ΔV_{OUT}/(V_{OUT}·ΔTopr)$	-40°C≦Topr≦85°C.	-	±100	-	ppm/°C	②
CE "High" Voltage	V_{CEH}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while $V_{CE}=0.2→1.5V$.	1.2	-	6.0	V	⑤
CE "Low" Voltage	V_{CEL}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{CE}=1.5→0.2V$.	GND	-	0.3	V	⑤
CE "High" Current	I_{CEH}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	µA	⑤
CE "Low" Current	I_{CEL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, L_X=Open.	-0.1	-	0.1	µA	⑤
Short Protection Threshold Voltage	V_{SHORT}	Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{OUT}=V_{OUT(T)}+0.1V→0V$ [*1].	0.4	0.5	0.6	V	②
C_L Discharge	R_{DCHG}	$V_{IN}=V_{OUT}=5.0V$, $V_{CE}=0V$, L_X=Open.	55	80	105	Ω	③
Inductance Value	L	Test Frequency=1MHz	-	8.0	-	µH	
(Coil) Rated Current	I_{DC_L}	ΔT=+40°C	-	600	-	mA	

Unless otherwise stated, $V_{IN}=V_{CE}=5.0V$

[*1] $V_{OUT(T)}$=Nominal Output Voltage

[*2] $V_{OUT(E)}$=Effective Output Voltage

The actual output voltage value $V_{OUT(E)}$ is the PFM comparator threshold voltage in the IC.

Therefore, the DC/DC circuit output voltage, including the peripheral components, is boosted by the ripple voltage average value.

Please refer to the characteristic example.

[*3] Not applicable to the products with $V_{OUT(T)}$ < 2.2V since it is out of operational volatge range.

[*4] EFFI=[{ (Output Voltage)×(Output Current)] / [(Input Voltage)×(Input Current)}]×100

[*5] L_X SW "Pch" ON resistance = (V_{IN} – V_{LX} pin measurement voltage) / 100mA

[*6] Designed value

■ELECTRICAL CHARACTERISTICS (Continued)

●XCL210Dxx1GR-G, with C_L Discharge Function

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}	-	2.0	-	6.0	V	①
Output Voltage	$V_{OUT(E)}$ [2]	Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{OUT} is decreasing.		E1		V	②
UVLO Release Voltage	$V_{UVLO(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while V_{IN} is increasing.	1.65	1.80	1.95	V	②
UVLO Hysteresis Voltage	$V_{HYS(E)}$	$V_{CE}=V_{IN}$, $V_{OUT}=0V$. Resistor connected with L_X pin. $V_{UVLO(E)}$ - Voltage which L_X pin changes "H" to "L" level while V_{IN} is decreasing.	0.11	0.15	0.24	V	②
Supply Current	Iq	$V_{IN}=V_{CE}=V_{OUT(T)}+0.5V$ [1], $V_{IN}=2.0V$, if $V_{OUT(T)}≦1.5V$ [1], $V_{OUT}=V_{OUT(T)}+0.5V$ [1], $L_X=$Open.		E2		μA	③
Standby Current	I_{STB}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $L_X=$Open.	-	0.1	1.0	μA	③
L_X SW "H" Leak Current	I_{LEAKH}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=0V$.	-	0.1	1.0	μA	③
L_X SW "L" Leak Current	I_{LEAKL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $V_{LX}=5.0V$.	-	0.1	1.0	μA	③
PFM Switching Current	I_{PFM}	$V_{IN}=V_{CE}=V_{OUT(T)}+2.0V$ [1], $I_{OUT}=10mA$.	115	180	250	mA	①
Maximum Duty Ratio [3]	MAXDTY	$V_{IN}=V_{OUT}=V_{OUT(T)}×0.95V$ [1], $V_{CE}=1.2V$ Resistor connected with L_X pin.	100	-	-	%	②
Efficiency [4]	EFFI	$V_{IN}=V_{CE}=5.0V$, $V_{OUT(T)}=4.0V$ [1], $I_{OUT}=30mA$.	-	95	-	%	①
Efficiency [4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=3.3V$ [1], $I_{OUT}=30mA$.	-	95	-	%	①
Efficiency [4]	EFFI	$V_{IN}=V_{CE}=3.6V$, $V_{OUT(T)}=1.8V$ [1], $I_{OUT}=30mA$.	-	89	-	%	①
L_X SW "Pch" ON Resistance [5]	R_{LXP}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, $I_{LX}=100mA$.	-	0.4	0.65	Ω	④
L_X SW "Nch" ON Resistance	R_{LXN}	$V_{IN}=V_{CE}=5.0V$.	-	0.4 [6]	-	Ω	-
Output Voltage Temperature Characteristics	$\Delta V_{OUT}/(V_{OUT}\cdot\Delta Topr)$	$-40°C≦Topr≦85°C$.	-	±100	-	ppm/°C	②
CE "High" Voltage	V_{CEH}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "L" to "H" level while $V_{CE}=0.2→1.5V$.	1.2	-	6.0	V	⑤
CE "Low" Voltage	V_{CEL}	$V_{OUT}=0V$. Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{CE}=1.5→0.2V$.	GND	-	0.3	V	⑤
CE "High" Current	I_{CEH}	$V_{IN}=V_{CE}=5.0V$, $V_{OUT}=0V$, $L_X=$Open.	-0.1	-	0.1	μA	⑤
CE "Low" Current	I_{CEL}	$V_{IN}=5.0V$, $V_{CE}=V_{OUT}=0V$, $L_X=$Open.	-0.1	-	0.1	μA	⑤
Short Protection Threshold Voltage	V_{SHORT}	Resistor connected with L_X pin. Voltage which L_X pin changes "H" to "L" level while $V_{OUT}=V_{OUT(T)}+0.1V→0V$ [1].	0.4	0.5	0.6	V	②
C_L Discharge	R_{DCHG}	$V_{IN}=V_{OUT}=5.0V$, $V_{CE}=0V$, $L_X=$Open.	55	80	105	Ω	③
Inductance Value	L	Test Frequency=1MHz	-	8.0	-	μH	
Rated Current	I_{DC}	$\Delta T=+40°C$	-	600	-	mA	

Unless otherwise stated, $V_{IN}=V_{CE}=5.0V$
[1] $V_{OUT(T)}$=Nominal Output Voltage
[2] $V_{OUT(E)}$=Effective Output Voltage
The actual output voltage value $V_{OUT(E)}$ is the PFM comparator threshold voltage in the IC.
Therefore, the DC/DC circuit output voltage, including the peripheral components, is boosted by the ripple voltage average value.
Please refer to the characteristic example.
[3] Not applicable to the products with $V_{OUT(T)}$< 2.2V since it is out of operational volatge range.
[4] EFFI=[{ (Output Voltage)×(Output Current)] / [(Input Voltage)×(Input Current)}]×100
[5] L_X SW "Pch" ON resistance = (V_{IN} – V_{LX} pin measurement voltage) / 100mA
[6] Designed value

■ELECTRICAL CHARACTERISTICS (Continued)

XCL210 Series voltage chart

SYMBOL	E1		E2		SYMBOL	E1		E2	
PARAMETER	OUTPUT VOLTAGE		SUPPLY CURRENT		PARAMETER	OUTPUT VOLTAGE		SUPPLY CURRENT	
UNITS: V	UNITS: V		UNITS: µA		UNITS: V	UNITS: V		UNITS: µA	
OUTPUT VOLTAGE	MIN.	MAX.	TYP.	MAX.	OUTPUT VOLTAGE	MIN.	MAX.	TYP.	MAX.
1.0	0.980	1.020			2.5	2.450	2.550		
1.1	1.078	1.122			2.6	2.548	2.652		
1.2	1.176	1.224	0.5	0.8	2.7	2.646	2.754	0.7	1.5
1.3	1.274	1.326			2.8	2.744	2.856		
1.4	1.372	1.428			2.9	2.842	2.958		
1.5	1.470	1.530			3.0	2.940	3.060		
1.6	1.568	1.632			3.1	3.038	3.162		
1.7	1.666	1.734	0.5	0.9	3.2	3.136	3.264	0.8	2.1
1.8	1.764	1.836			3.3	3.234	3.366		
1.9	1.862	1.938			3.4	3.332	3.468		
2.0	1.960	2.040			3.5	3.430	3.570		
2.1	2.058	2.142			3.6	3.528	3.672		
2.2	2.156	2.244	0.6	1.1	3.7	3.626	3.774	1.5	3.0
2.3	2.254	2.346			3.8	3.724	3.876		
2.4	2.352	2.448			3.9	3.822	3.978		
					4.0	3.920	4.080		

■TYPICAL APPLICATION CIRCUIT
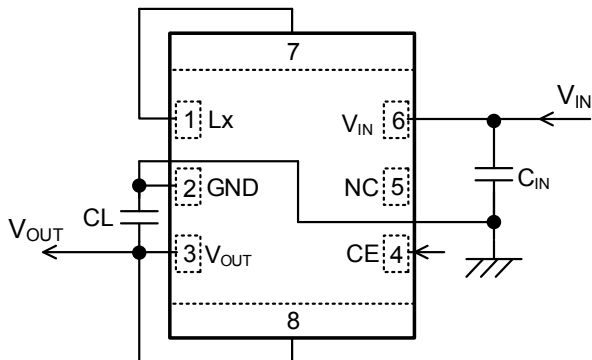
NOTE:
The integrated Inductor can be used only for this DC/DC converter. Please do not use this inductor for other reasons.

	Manufacturer	Part Number	VALUE
C_{IN}	Taiyo Yuden	LMK107BBJ106MALT	10µF/10V
		LMK212ABJ106MG	10µF/10V
	TDK	C1608X5R1A106M	10µF/10V
		C2012X5R1A106M	10µF/10V
CL	Taiyo Yuden	LMK107BBJ226MA	22µF/10V
		LMK212BBJ226MG	22µF/10V
	TDK	C1608X5R1A226M	22µF/10V
		C2012X5R1A226M	22µF/10V

* Take capacitance loss, withstand voltage, and other conditions into consideration when selecting components.

■ OPERATIONAL EXPLANATION

The XCL210 series consists of a reference voltage supply, PFM comparator, Pch driver Tr, Nch synchronous rectification switch Tr, current sensing circuit, PFM control circuit, CE control circuit, and others. (Refer to the block diagram below.)
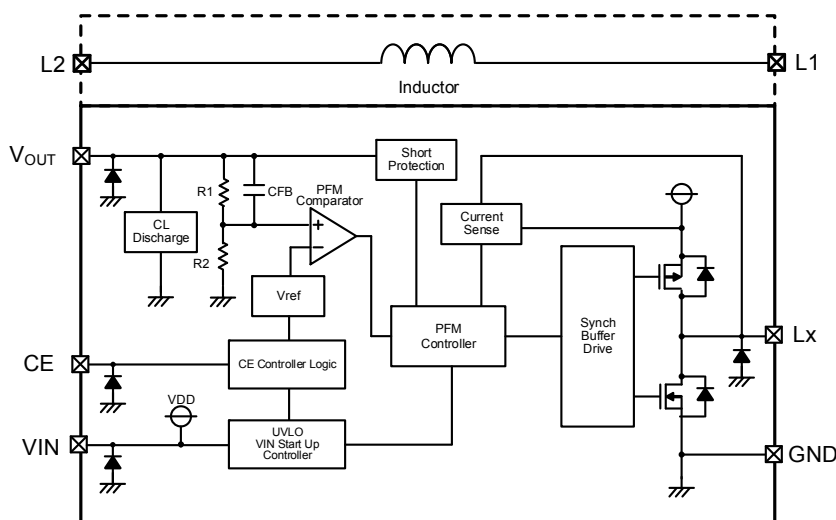
An ultra-low quiescent current circuit and synchronous rectification enable a significant reduction of dissipation in the IC, and the IC operates with high efficiency at both light loads and heavy loads. Current limit PFM is used for the control method, and even when switching current superposition occurs, increases of output voltage ripple are suppressed, allowing use over a wide voltage and current range. The IC is compatible with low-capacitance ceramic capacitors, and a small, high-performance step-down DC-DC converter can be created.

The actual output voltage $V_{OUT(E)}$ in the electrical characteristics is the threshold voltage of the PFM comparator in the block diagram. Therefore the average output voltage of the step-down circuit, including peripheral components, depends on the ripple voltage. Before use, test fully using the actual device.

$V_{IN}=V_{CE}=3.6V$、$V_{OUT}=1.8V$、$I_{OUT}=5mA$、$L=8.0\mu H$、$C_L=22uF$、$Ta=25°C$ $V_{IN}=V_{CE}=3.6V$、$V_{OUT}=1.8V$、$I_{OUT}=30mA$、$L=8.0\mu H$、$C_L=22uF$、$Ta=25°C$

10[μs/div]   10[μs/div]

<Reference voltage supply (V_{REF})>
Reference voltage for stabilization of the output voltage of the IC.

<PFM control>
(1) The feedback voltage (FB voltage) is the voltage that results from dividing the output voltage with the IC internal dividing resistors R_{FB1} and R_{FB2}. The PFM comparator compares this FB voltage to V_{REF}. When the FB voltage is lower than V_{REF}, the PFM comparator sends a signal to the buffer driver through the PFM control circuit to turn on the Pch driver Tr. When the FB voltage is higher than V_{REF}, the PFM comparator sends a signal to prevent the Pch driver Tr from turning on.

(2) When the Pch driver Tr is on, the current sense circuit monitors the current that flows through the Pch driver Tr connected to the Lx pin. When the current reaches the set PFM switching current (I_{PFM}), the current sense circuit sends a signal to the buffer driver through the PFM control circuit. This signal turns off the Pch driver Tr and turns on the Nch synchronous rectification switch Tr.

(3) The on time (off time) of the Nch synchronous rectification switch Tr is dynamically optimized inside the IC. After the off time elapses and the PFM comparator detects that the V_{OUT} voltage is higher than the set voltage, the PFM comparator sends a signal to the PFM control circuit that prevents the Pch driver Tr from turning on. However, if the V_{OUT} voltage is lower than the set voltage, the PFM comparator starts Pch driver Tr on.

■OPERATIONAL EXPLANATION (Continued)

By continuously adjusting the interval of the linked operation of (1), (2) and (3) above in response to the load current, the output voltage is stabilized with high efficiency from light loads to heavy loads.

<PFM Switching Current >
The PFM switching current monitors the current that flows through the Pch driver Tr, and is a value that limits the Pch driver Tr current.
The Pch driver Tr remains on until the coil current reaches the PFM switching current (I_{PFM}). An approximate value for this on-time t_{ON} can be calculated using the following equation:
$t_{ON} = L \times I_{PFM} / (V_{IN} - V_{OUT})$

<Maximum on-time function>
To avoid excessive ripple voltage in the event that the coil current does not reach the PFM switching current within a certain interval even though the Pch driver Tr has turned on and the FB voltage is above V_{REF}, the Pch driver Tr can be turned off at any timing using the maximum on-time function of the PFM control circuit. If the Pch driver Tr turns off by the maximum on-time function instead of the current sense circuit, the Nch synchronous rectification switch Tr will not turn on and the coil current will flow to the V_{OUT} pin by means of the parasite diode of the Nch synchronous rectification switch Tr.

<Through mode>
When the V_{IN} voltage is lower than the output voltage, through mode automatically activates and the Pch driver Tr stays on continuously.
(1) In through mode, when the load current is increased and the current that flows through the Pch driver Tr reaches a load current that is several tens of mA lower than the set PFM switching current (I_{PFM}), the current sense circuit sends a signal through the PFM control circuit to the buffer driver. This signal turns off the Pch driver Tr and turns on the Nch synchronous rectification switch Tr.
(2) After the on-time (off-time) of the Nch synchronous rectification switch Tr, the Pch driver Tr turns on until the current reaches the set PFM switching current (I_{PFM}) again.

If the load current is large as described above, operations (1) and (2) above are repeated. If the load current is several tens of mA lower than the PFM switching current (I_{PFM}), the Pch driver Tr stays on continuously.

<V_{IN} start mode>
When the V_{IN} voltage rises, V_{IN} start mode stops the short-circuit protection function during the interval until the FB voltage approaches V_{REF}. After the V_{IN} voltage rises and the FB voltage approaches V_{REF} by step-down operation, V_{IN} start mode is released. In order to prevent an excessive rush current while V_{IN} start mode is activated, the coil current flows to the V_{OUT} pin by means of the parasitic diode of the Nch synchronous rectification Tr. In V_{IN} start mode as well, the coil current is limited by the PFM switching current.

<Short-circuit protection function>
The short-circuit protection function monitors the V_{OUT} voltage. In the event that the V_{OUT} pin is accidentally shorted to GND or an excessive load current causes the V_{OUT} voltage to drop below the set short-circuit protection voltage, the short-circuit protection function activates, and turns off and latches the Pch driver Tr at any selected timing. Once in the latched state, the IC is turned off and then restarted from the CE pin, or operation is started by re-applying the V_{IN} voltage.

<UVLO function>
When the V_{IN} pin voltage drops below the UVLO detection voltage, the IC stops switching operation at any selected timing, turns off the Pch driver Tr and Nch synchronous rectification switch Tr (UVLO mode). When the V_{IN} pin voltage recovers and rises above the UVLO release voltage, the IC restarts operation.

<C_L discharge function>
On the XCL210 series, a C_L discharge function is available as an option (XCL210C/XCL210D types). This function enables quick discharging of the C_L load capacitance when "L" voltage is input into the CE pin by the Nch Tr connected between the V_{OUT}-GND pins, or in UVLO mode. This prevents malfunctioning of the application in the event that a charge remains on C_L when the IC is stopped. The discharge time is determined by C_L and the C_L discharge resistance R_{DCHG}, including the Nch Tr (refer to the diagram below). Using this time constant $\tau = C_L \times R_{DCHG}$, the discharge time of the output voltage is calculated by means of the equation below.

$V = V_{OUT} \times e^{-t/\tau}$, or in terms of t, $t = \tau \ln(V_{OUT} / V)$
V: Output voltage after discharge
V_{OUT} : Set output voltage
t: Discharge time
C_L: Value of load capacitance (C_L)
R_{DCHG} : Value of C_L discharge resistance Varies by power supply voltage.
τ : $C_L \times R_{DCHG}$
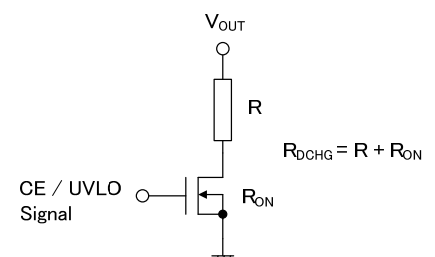
The C_L discharge function is not available on the XCL210A/XCL210B types.

■NOTE ON USE

1. Be careful not to exceed the absolute maximum ratings for externally connected components and this IC.

2. The DC/DC converter characteristics greatly depend not only on the characteristics of this IC but also on those of externally connected components, so refer to the specifications of each component and be careful when selecting the components. Be especially careful of the characteristics of the capacitor used for the load capacity C_L and use a capacitor with B characteristics (JIS Standard) or an X7R/X5R (EIA Standard) ceramic capacitor.

3. Use a ground wire of sufficient strength. Ground potential fluctuation caused by the ground current during switching could cause the IC operation to become unstable, so reinforce the area around the GND pin of the IC in particular.

4. Mount the externally connected components in the vicinity of the IC. Also use short, thick wires to reduce the wire impedance.

5. When the voltage difference between V_{IN} and V_{OUT} is small, switching energy increases and there is a possibility that the ripple voltage will be too large. Before use, test fully using the actual device.

6. The CE pin does not have an internal pull-up or pull-down, etc. Apply the prescribed voltage to the CE pin.

7. If other than the recommended inductance and capacitance values are used, excessive ripple voltage or a drop in efficiency may result.

8. If other than the recommended inductance and capacitance values are used, a drop in output voltage when the load is excessive may cause the short-circuit protection function to activate. Before use, test fully using the actual device.

9. At high temperature, excessive ripple voltage may occur and cause a drop in output voltage and efficiency. Before using at high temperature, test fully using the actual device

10. At light loads or when IC operation is stopped, leakage current from the Pch driver Tr may cause the output voltage to rise.

11. The average output voltage may vary due to the effects of output voltage ripple caused by the load current. Before use, test fully using the actual device.

12. If the C_L capacitance or load current is large, the output voltage rise time will lengthen when the IC is started, and coil current overlay may occur during the interval until the output voltage reaches the set voltage (refer to the diagram below).

XCL210A Series、$V_{IN}=V_{CE}=0\rightarrow6.0V$、$V_{OUT}=1.0V$、$I_{OUT}=200mA$、CL=22uF、Ta=25℃
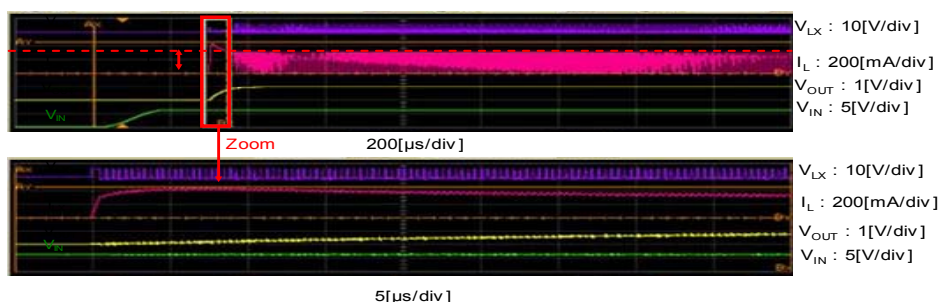
13. When the IC is started, the short-circuit protection function does not operate during the interval until the V_{OUT} voltage reaches a value near the set voltage.

14. If the IC is started at a V_{IN} voltage that activates through mode, it is possible that the short-circuit protection function will not operate. Before use, test fully using the actual device.

15. If the load current is excessively large when the IC is started, it is possible that the V_{OUT} voltage will not rise to the set voltage. Before use, test fully using the actual device.

■NOTE ON USE (Continued)

16. In actual operation, the maximum on-time depends on the peripheral components, input voltage, and load current. Before use, test fully using the actual device.

17. When the V_{IN} voltage is turned on and off continuously, excessive rush current may occur while the voltage is on. Before use, test fully using the actual device.

18. When the V_{IN} voltage is high, the Pch driver may change from on to off before the coil current reaches the PFM switching current (I_{PFM}), or before the maximum on-time elapses. Before use, test fully using the actual device.

19. When the IC change to the Through Mode at light load, the supply current of this IC can increase in some cases.

20. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.

21. Torex places an importance on improving our products and their reliability.
    We request that users incorporate fail-safe designs and post-aging protection treatment when using Torex products in their systems.

■NOTE ON USE (Continued)

●Instructions of pattern layouts

1. To suppress fluctuations in the V_{IN} potential, connect a bypass capacitor (C_{IN}) in the shortest path between the V_{IN} pin and ground pin.

2. Please mount each external component as close to the IC as possible.

3. Wire external components as close to the IC as possible and use thick, short connecting traces to reduce the circuit impedance.

4. Make sure that the ground traces are as thick as possible, as variations in ground potential caused by high ground currents at the time of switching may result in instability of the IC.

5. Internal driver transistors bring on heat because of the transistor current and ON resistance of the driver transistors.

●Recommended Pattern Layout
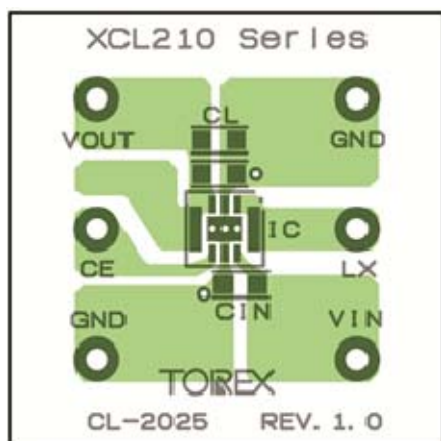
Top view
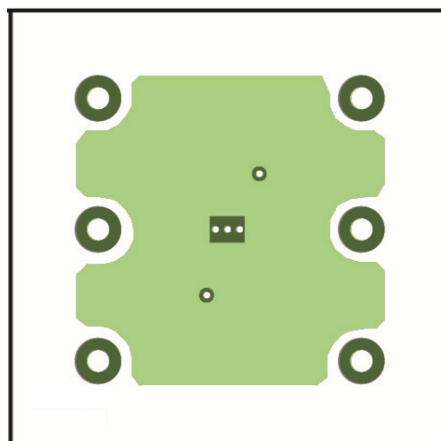
Back side top view

■TYPICAL PERFORMANCE CHARACTERISTICS

1）Output Voltage vs. Output Current
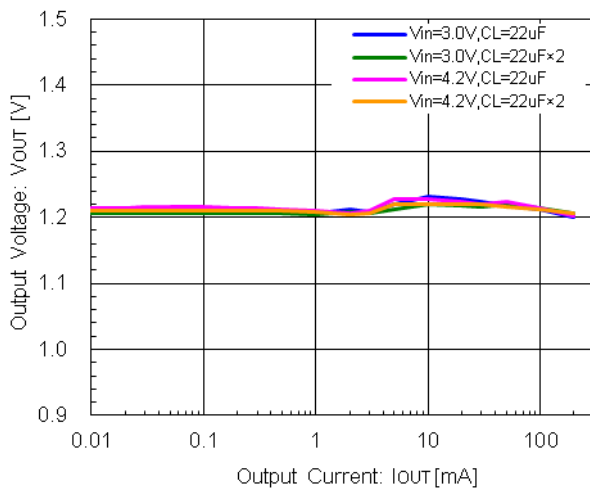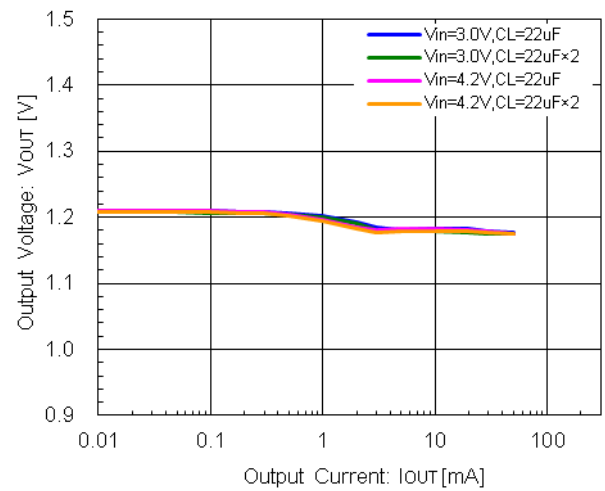
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XCL210B121GR-G/XCL210D121GR-G

XCL210A181GR-G/XCL210C181GR-G
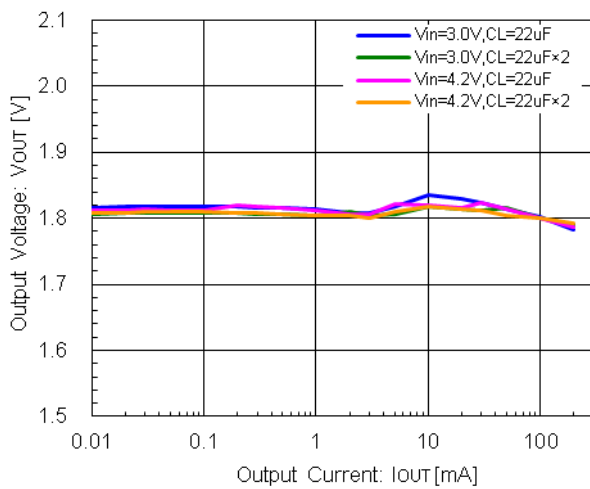
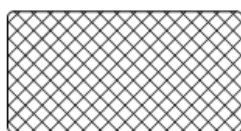XCL210B181GR-G/XCL210D181GR-G
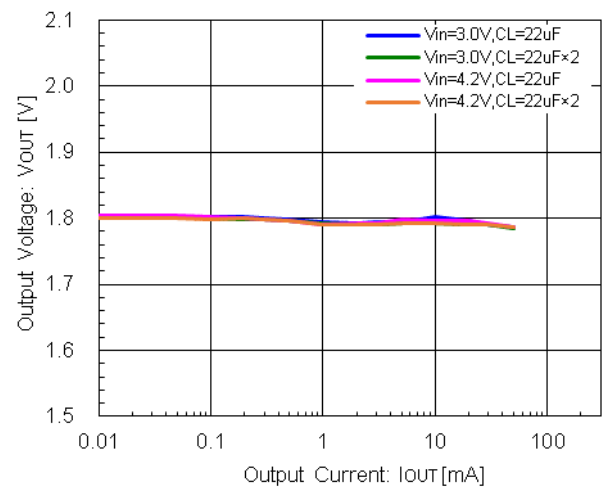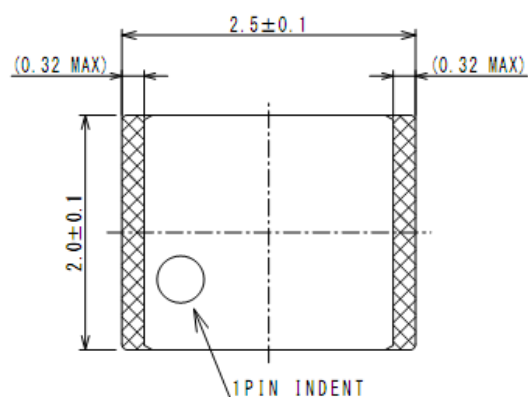

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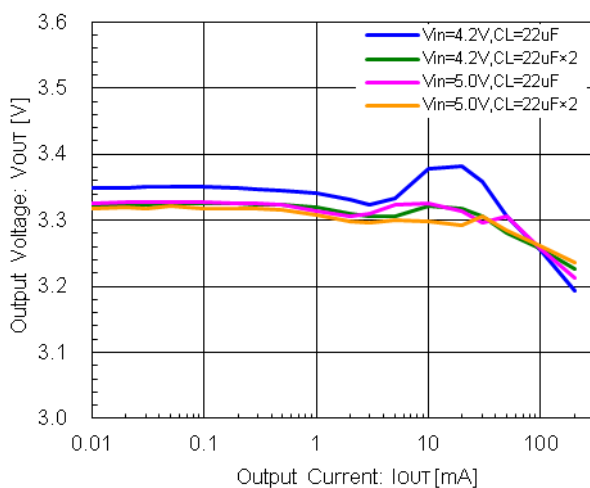

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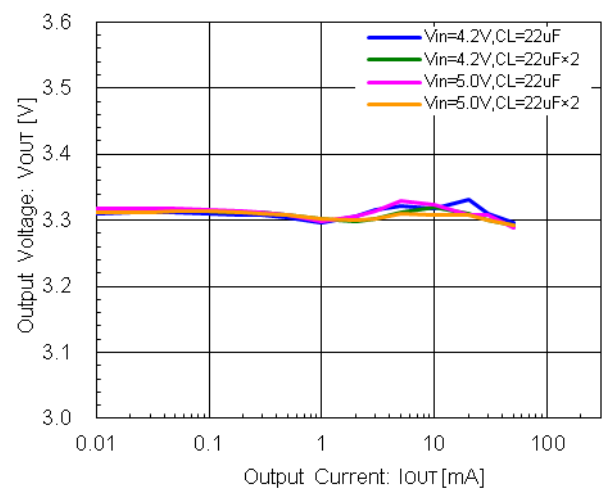
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

2）Efficiency vs. Output Current
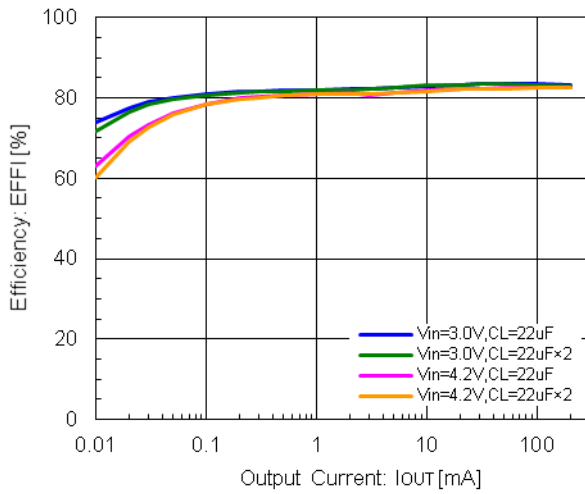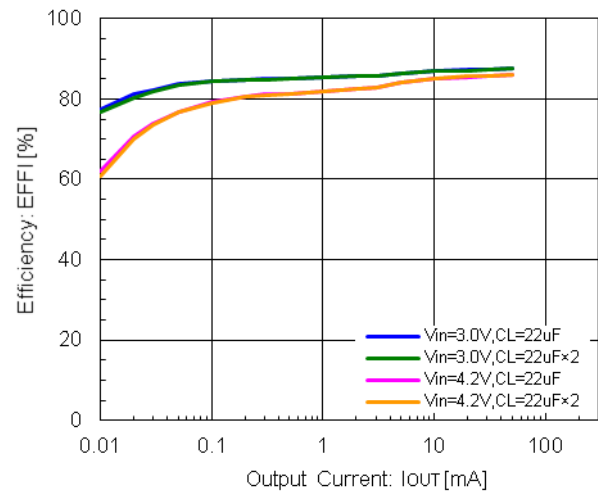
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XCL210B121GR-G/XCL210D121GR-G

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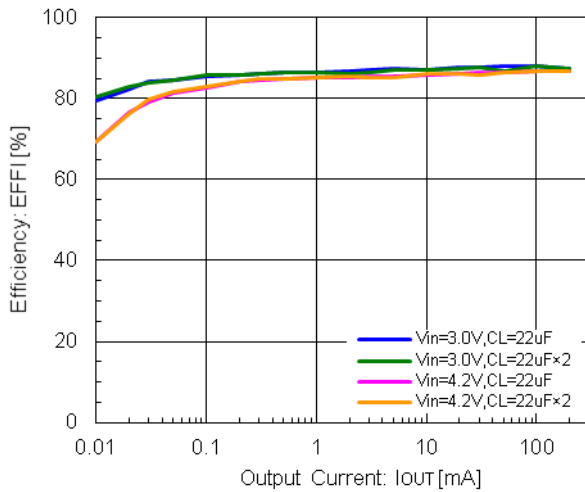
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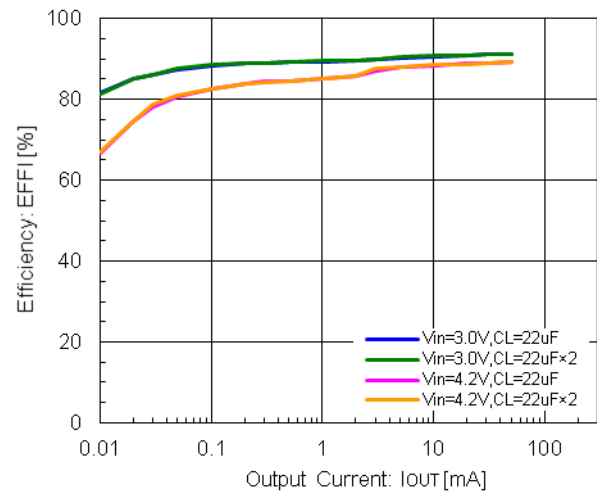
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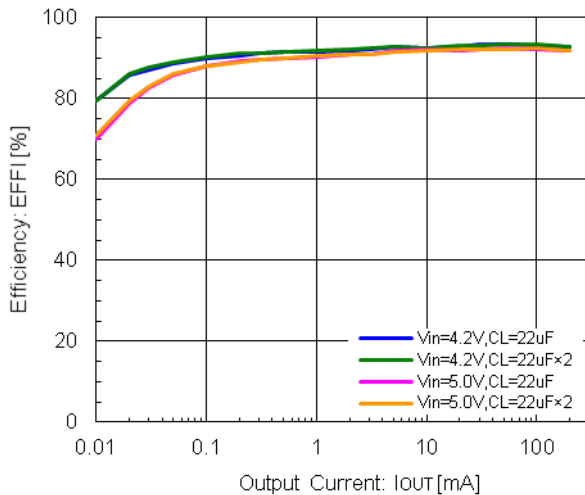
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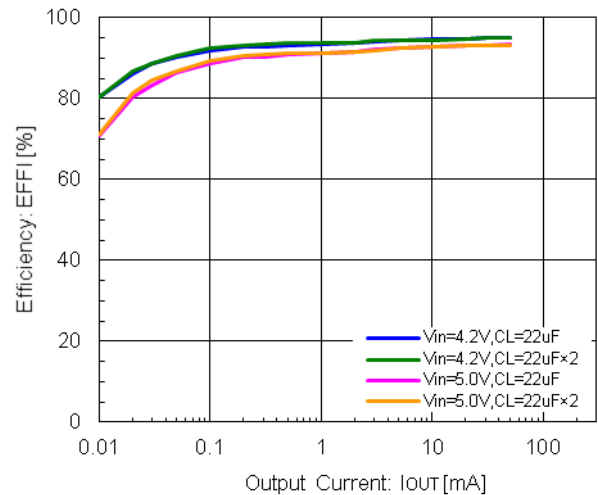
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

3) Ripple Voltage vs. Output Current
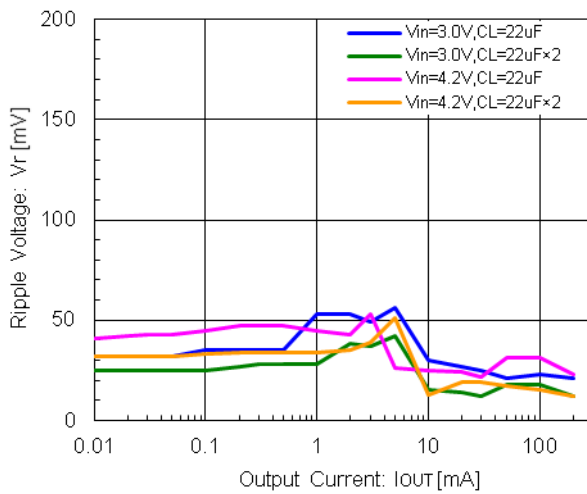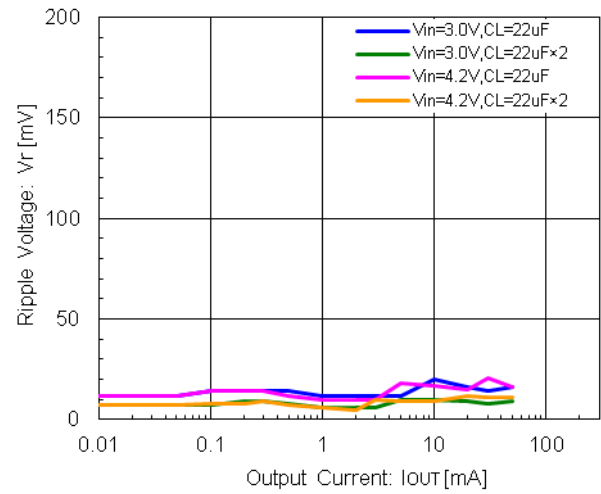
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XCL210B121GR-G/XCL210D121GR-G

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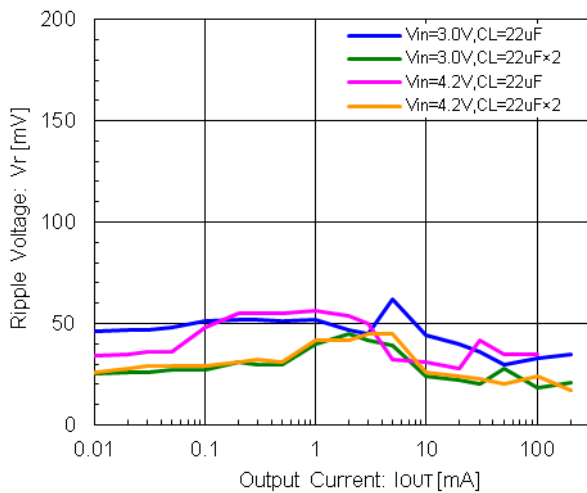
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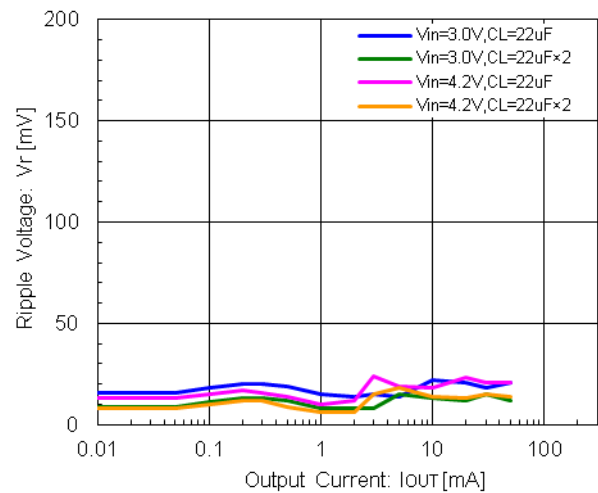
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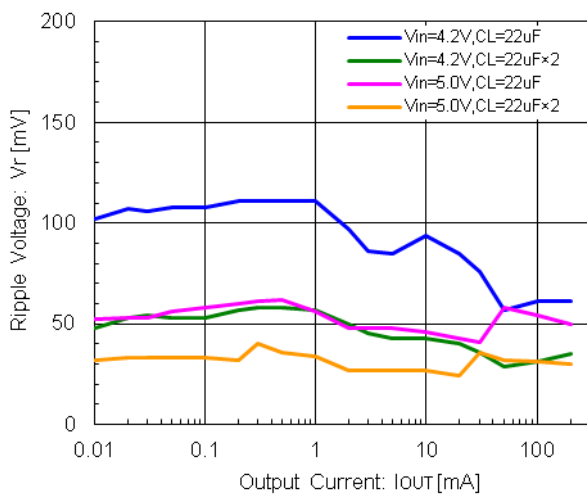
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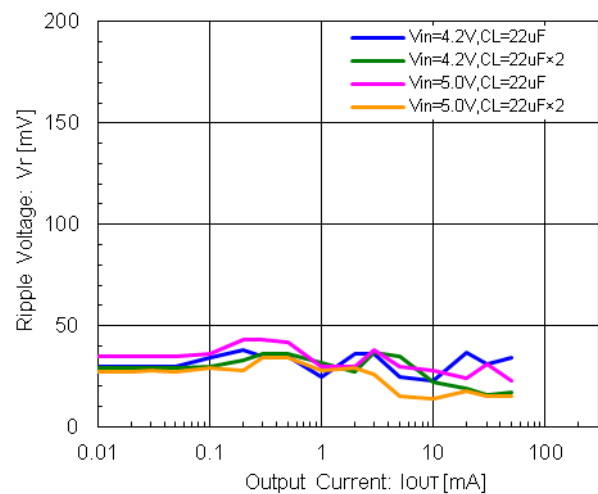
■PACKAGING INFORMATION

● CL-2025-02 (unit: mm)

2.5±0.1
(0.32 MAX)　(0.32 MAX)
2.0±0.1
1PIN INDENT

1.04 MAX

0.3±0.05
0.2±0.05
±0.1
1
2
3
7
0.2±0.05
1.1±0.05
8
6
5
4
(0.22 MAX)
(0.55)
(0.22 MAX)
(0.5)
1.5±0.05
(0.5)
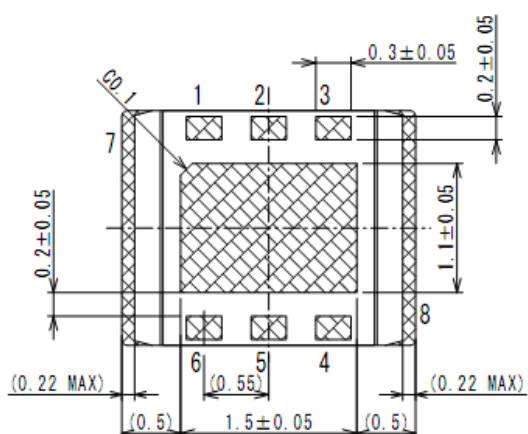
External Lead

⬚ Au min0.1um
⬚ Sn 1.5～3.5um

● Reference Pattern Layout (unit: mm)

2.9
0.35　1.5　0.35
0.35
0.375
0.375
1.1
2.1
2.25
0.55　0.55
0.35　2.2　0.35
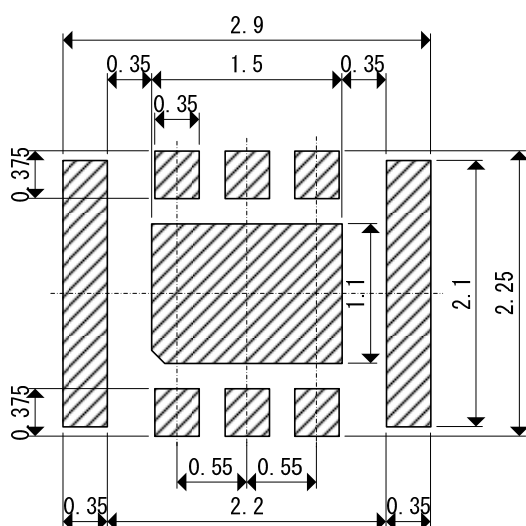
● Reference Metal Mask Design (unit: mm)

2.85
0.5　1.3　0.5
0.3
0.3
0.5
0.9
2.05
2.2
0.3
0.55　0.55
0.275　2.3　0.275
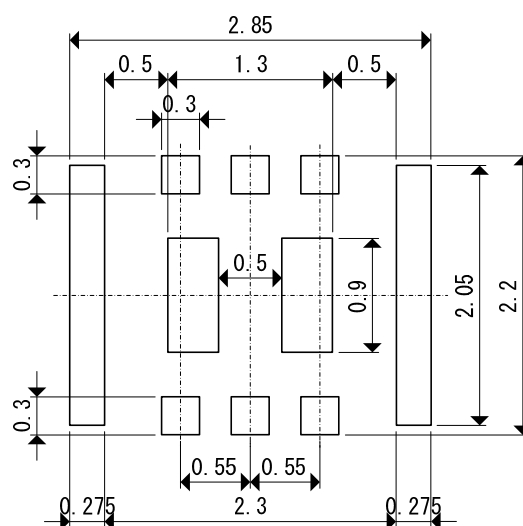
*Implementation of CL-2025-02 is recommended within accuracy 0.05mm.

■MARKING RULE

●CL-2025-02
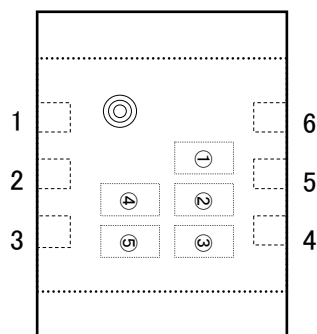
① represents products series

MARK	PRODUCT SERIES
0	XCL210******-G

② represents integer of the output voltage

MARK	Type	OUTPUT VOLTAGE(V)	PRODUCT SERIES
8	A	1.x	XCL210A1****-G
9		2.x	XCL210A2****-G
E		3.x	XCL210A3****-G
F		4.x	XCL210A4****-G
H	B	1.x	XCL210B1****-G
K		2.x	XCL210B2****-G
L		3.x	XCL210B3****-G
M		4.x	XCL210B4****-G
N	C	1.x	XCL210C1****-G
P		2.x	XCL210C2****-G
R		3.x	XCL210C3****-G
S		4.x	XCL210C4****-G
T	D	1.x	XCL210D1****-G
U		2.x	XCL210D2****-G
V		3.x	XCL210D3****-G
X		4.x	XCL210D4****-G
Y	Custom		XCL210S*****-G

③ represents the decimal part of output voltage

OUTPUT VOLTAGE(V)	MARK	PRODUCT SERIES
X.0	0	XCL210**0***-G
X.1	1	XCL210**1***-G
X.2	2	XCL210**2***-G
X.3	3	XCL210**3***-G
X.4	4	XCL210**4***-G
X.5	5	XCL210**5***-G
X.6	6	XCL210**6***-G
X.7	7	XCL210**7***-G
X.8	8	XCL210**8***-G
X.9	9	XCL210**9***-G

④,⑤ represents production lot number

01～09、0A～0Z、11～9Z、A1～A9、AA～AZ、B1～ZZ in order.

(G, I, J, O, Q, W excluded)

Note: No character inversion used.